

STTH1L06

Turbo 2 ultrafast high voltage rectifier

Features

- Ultrafast switching
- Low reverse recovery current
- Reduces switching and conduction losses
- Low thermal resistance

Description

The STTH1L06/U/A, which is using ST Turbo 2 600 V technology, is specially suited as boost diode in discontinuous or critical mode power factor corrections.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.

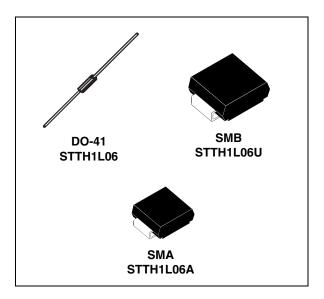


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V _{RRM}	600 V
I _R (max)	75 µA
T _j (max)	175 °C
V _F (max)	1.05 V
t _{rr} (max)	80 ns

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Characteristics 1

Table 2. Absolute ratings (limiting values)

Symbol	Pa	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage	Repetitive peak reverse voltage			V
1	Forward rms voltage	DO-41		10	Α
I _F (RMS)	Forward rms voltage SMA / SMB			7	
		DO-41	T _c = 120 °C		
I _{F(AV)}	Average forward current $\delta = 0.5$	SMA	T _c = 135 °C	1	Α
		SMB	T _c = 145 °C		
I _{FSM}	Surge non repetitive forward current	t_p = 10 ms sinusoidal DO-41 t_p = 10 ms sinusoidal SMA / SMB		30 20	А
T _{stg}	Storage temperature range			-65 to + 175	°C
Tj	Maximum operating junction temperature			175	°C

Table 3. Thermal parameters

Symbol	Parameter			Value (max)	Unit
		L = 10 mm	DO-41	45	
R _{th(j-l)}	Junction to lead		SMA	30	°C/W
			SMB	25	C/VV
R _{th(j-a)}	Junction to ambient ⁽¹⁾	L = 10 mm	DO-41	70	

^{1.} Rth(j-a) is measured with a copper area $S = 5 \text{ cm}^2$ (see *Figure 14*.)

Static electrical characteristics Table 4.

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	Reverse leakage current	T _j = 25 °C	V = 600 V			1	
I'R	$T_j = 150 ^{\circ}\text{C}$	$T_j = 150 ^{\circ}\text{C}$ $V_R = 600 \text{V}$			10	75	μΑ
V _F	Forward voltage drop	T _j = 25 °C	Ι _ 1 Λ			1.3	V
V _F	Forward voltage drop	T _j = 150 °C	$T_j = 150 ^{\circ}\text{C}$ $I_F = 1 \text{A}$		0.85	1.05	V

To evaluate the conduction losses use the following equation: P = 0.89 x $I_{F(AV)}$ + 0.165 $I_{F}^{\ 2}_{(RMS)}$

$$P = 0.89 \text{ x } I_{F(AV)} + 0.165 I_{F(RMS)}^2$$

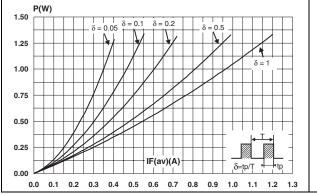
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Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
t _{rr}	Reverse recovery time	T _j = 25 °C	$I_F = 1 \text{ A}, dI_F/dt = -50, A/\mu s, V_R = 30 \text{ V}$		55	80	ns
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$ $V_{FR} = 3.5 \text{ V}$			50	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}$			10	V

Figure 1. Conduction losses versus average current

Figure 2. Forward voltage drop versus forward current



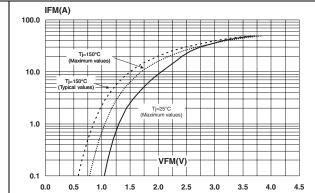
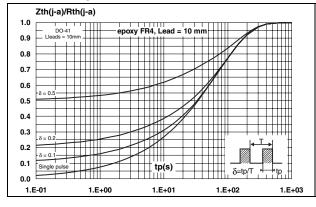
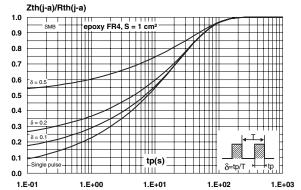


Figure 3. Relative variation of thermal impedance junction ambient versus pulse duration

Figure 4. Relative variation of thermal impedance junction ambient versus pulse duration





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Figure 5. Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4)

Figure 6. Peak reverse recovery current versus dl_F/dt (90% confidence)

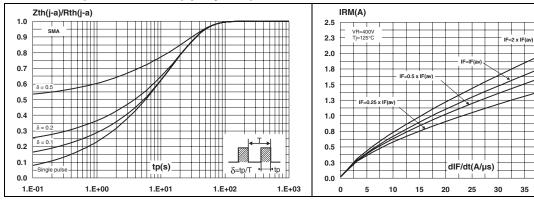


Figure 7. Reverse recovery time versus dl_F/dt Figure 8. Reverse recovery charges versus dl_F/dt (90% confidence)

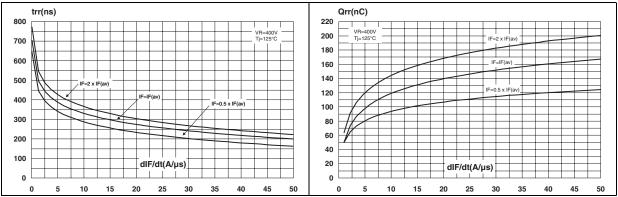
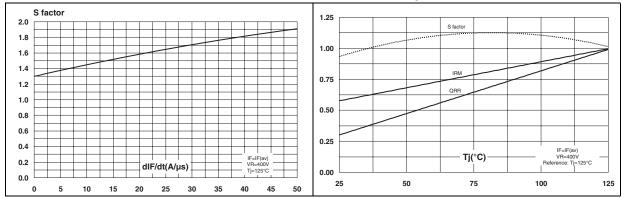


Figure 9. Softness factor versus dl_F/dt (typical values)

Figure 10. Relative variations of dynamic parameters versus junction temperature

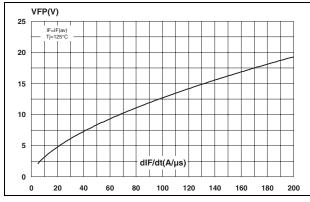


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Figure 11. Transient peak forward voltage versus dl_F/dt (90% confidence)

Figure 12. Forward recovery time versus dl_F/dt (90% confidence)

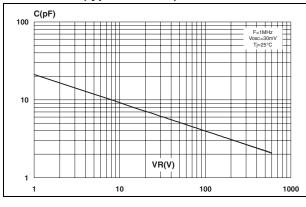


tfr(ns)

200
180
160
140
120
100
80
60
40
20
0 20 40 60 80 100 120 140 160 180 200

Figure 13. Junction capacitance versus reverse voltage applied (typical values)

Figure 14. Thermal resistance junction to ambient versus copper surface under each lead



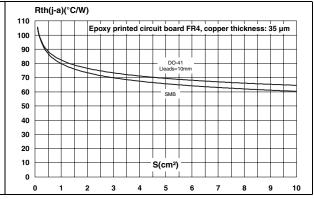
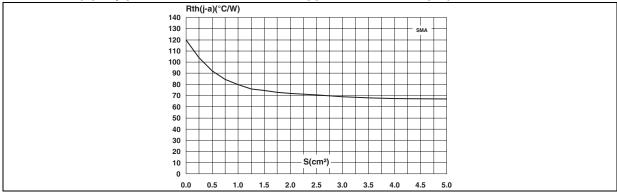


Figure 15. Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: 35 μm)



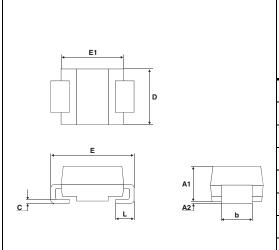
Package information STTH1L06

2 Package information

- Epoxy meets UL 94, V0
- Band indicates cathode
- Bending method (DO-41): see Application note AN1471

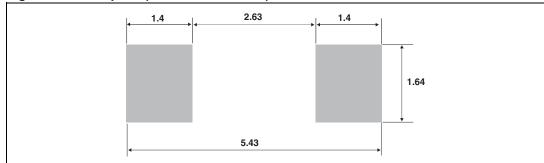
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Table 6. SMA dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.075	0.094		
A2	0.05	0.20	0.002	0.008		
b	1.25	1.65	0.049	0.065		
С	0.15	0.40	0.006	0.016		
D	2.25	2.90	0.089	0.114		
Е	4.80	5.35	0.189	0.211		
E1	3.95	4.60	0.156	0.181		
L	0.75	1.50	0.030	0.059		

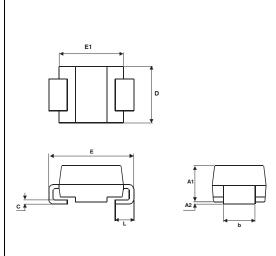
Figure 16. Footprint (dimensions in mm)



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Table 7. SMB dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.075	0.096		
A2	0.05	0.20	0.002	0.008		
b	1.95	2.20	0.077	0.087		
С	0.15	0.40	0.006	0.016		
D	3.30	3.95	0.130	0.156		
Е	5.10	5.60	0.201	0.220		
E1	4.05	4.60	0.159	0.181		
L	0.75	1.50	0.030	0.059		

Figure 17. Footprint (dimensions in mm)

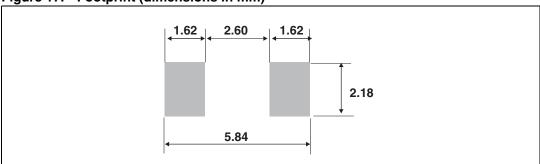
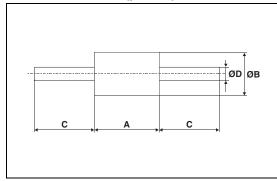


Table 8. DO-41 (plastic) dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	4.07	5.20	0.160	0.205		
В	2.04	2.71	0.080	0.107		
С	25.4		1			
D	0.71	0.86	0.028	0.034		

Ordering information STTH1L06

3 Ordering information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH1L06	STTH1L06	DO-41	0.34 g	2000	Ammopack
STTH1L06RL	STTH1L06	DO-41	0.34 g	5000	Tape and reel
STTH1L06U	BL6	SMB	0.11 g	2500	Tape and reel
STTH1L06A	HL6	SMA	0.068 g	5000	Tape and reel

4 Revision history

Table 10. Document revision history

Date	Revision	Changes
Jul-2002	3C	Last issue.
30-Sep-2009	4	Updated table 8 package dimensions.

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